20 V - 250 V Driver for High Power PIN Diode Switches



MADR-010574

Rev. V4

Features

- 20 V 250 V Back Bias in Off State
- 200 mA Series Diode Bias Current @ +25°C
- 50 mA Shunt Diode Bias Current @ +25°C
- Propagation Delay <8 µs
- Low Quiescent Current Consumption
- 3 V or 5 V CMOS Logic Control
- 7 mm QFN-16LD Package
- Tape and Reel Packaging Available
- RoHS* Compliant and 260°C Reflow Compatible

Applications

- Aerospace & Defense
- ISM

Description

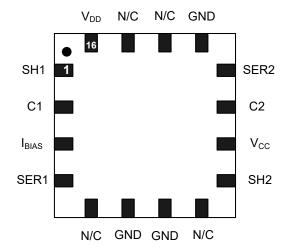
The MADR-010574 switch driver is designed to work with MACOMs high power and high voltage PIN diodes. This driver consists of two independently controlled drivers which are able to provide 200 mA series / 50 mA shunt current to a series / shunt, SPDT PIN diode switch. The back bias voltage is configurable from 20 V to 250 V. High voltage level shifters are integrated so that it can be easily controlled by 3 V or 5 V CMOS logic. While consuming low quiescent current, this driver has a typical delay of <8 µs when driving 220 pF capacitor load. If needed, the switching speed can be improved by consuming more quiescent power.

This driver is packaged in a lead free 7 mm PQFN-16LD package and is available in tape and reel packaging for high volume applications.

Ordering Information

Part Number	Package
MADR-010574-000100	Bulk Packaging
MADR-010574-0001TR	1000 piece Reel
MADR-010574-001SMB	Sample Board with Driver & MA4P504-1072T Diodes

Functional Schematic



Pin Configuration ¹

Pin#	Pin Name	Description
1	SH1	Shunt1
2	C1	Control Logic 1
3	I _{BIAS}	Bias Voltage
4	SER1	Series1
5, 8, 14, 15	N/C ²	No Connection
6, 7, 13	GND	Ground
9	SH2	Shunt2
10	V _{CC}	Control Voltage
11	C2	Control Logic 2
12	SER2	Series2
16	V_{DD}	Drain Voltage
17	Paddle	Ground

^{1.} The paddle of the QFN package should be tied to ground.

N/C pins (except pin 15) can be grounded. The clearance from high voltage pins should be at least 0.8 mm. Pin 15 must be left open.

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



Rev. V4

Recommended Operating Conditions

Parameter	Test Conditions	Unit	Min.	Тур.	Max.
V _{CC}	Nominal $V_{CC} = 3.3 \text{ V}$ Nominal $V_{CC} = 5.0 \text{ V}$	V	3.0 4.5	3.3 5.0	3.6 5.5
V_{DD}	_	V	20	_	250
Control1, Control2 ³	Logic "0" Logic "1"	V	0.0 0.7 × V _{CC}	0.0 V _{CC}	$0.3 \times V_{CC}$ V_{CC}
Series1/Series2 Sinking Current ⁴	-40°C +25°C +85°C	mA	_	_	300 200 150
Shunt1/Shunt2 Sinking Current ⁴	-40°C +25°C +85°C	mA	_	_	65 55 50
I _{BIAS} ^{5,6}	+25°C	μA	2	6	150
Operating Temperature	_	°C	-40	+25	+85

3. Unused Controls should be either grounded or connected to V_{CC}. They should never be left open.

Refer to "Application Circuit: Driving SPDT Switch with MA4P504-1072T Pin Diodes" for configuration of diode bias currents.

This sinking bias current is necessary for normal driver operation. The easiest way is to connect a 0402 resistor R_{BIAS} between Pin V_{CC} and

Pin I_{BIAS} . Then I_{BIAS} can be calculated by: $I_{BIAS} = (V_{CC}-0.6)/(500+R_{BIAS})$. Refer to graph "Typ. Ton Driving 220 pF Capacitance vs. I_{BIAS} " on page 3 and the chart "Typ. I_{DD} vs. I_{BIAS} at 25°C" on page 4 for the tradeoff between switching speed and power consumption.

Absolute Maximum Ratings ^{7,8}

Parameter	Absolute Maximum
V _{CC}	-0.5 V to +7 V
V_{DD}	-0.5 V to 275 V
C1, C2 (Logic)	-0.5 V to 7 V
Series1/Series2 Sinking Current -40°C +25°C +85°C	550 mA 450 mA 350 mA
Shunt1/Shunt2 Sinking Current -40°C +25°C +85°C	150 mA 150 mA 100 mA
Series/Shunt Outputs Sourcing Current	25 mA
I _{BIAS}	500 μΑ
ESD HBM Rating	>1 kV
Operating Temperature	-40 to +125°C
Storage Temperature	-55 to +150°C

^{7.} MACOM does not recommend sustained operation near these survivability limits.

Truth Table 9

C1	C2	Series1	Shunt1	Series2	Shunt2
0	0	Low	High	Low	High
0	1	Low	High	High	Low
1	0	High	Low	Low	High
1	1	High	Low	High	Low

^{9.} The actual voltage levels for "Low" and "High" are dependent on the current load to the driver. They can be estimated from the driver on resistance.

Powering On/Off Sequence:

V_{DD} should be turned on after V_{CC}, and the rise time of V_{DD} should be slower than 2.5 μ s. When powering off, V_{DD} should be turned off before V_{CC} .

^{8.} Exceeding any one or combination of these limits may cause permanent damage to this device.



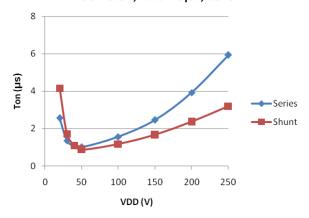
Rev. V4

Electrical Specifications: $T_A = +25$ °C, $V_{CC} = 3.3$ V, $V_{DD} = 250$ V, $I_{BIAS} = 6$ μA^{10}

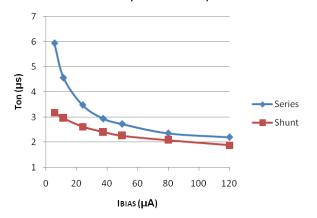
Parameter	Test Conditions	Unit	Min.	Тур.	Max.
Quiescent Supply Currents	V _{CC} (3.3 V) ¹¹ V _{DD} (250 V)	μA	_	6 25	10 37
Control Input Leakage Current	_	μA	_	_	1
Series Pull-down FET On Resistance	200 mA Load	Ω	_	9	11.4
Shunt Pull-down FET On Resistance	50 mA Load	Ω	_	26	30
Switching Speed Driving 220 pF Caps: Series ¹² T_{ON} T_{OFF} Tr Tf	50% CTL to 95% Voltage 50% CTL to 5% Voltage 10% - 90% 90% - 10%	μs	_	6.2 0.22 5.1 0.1	_
Switching Speed Driving 220 pF Caps: Shunt ¹² ToN ToFF Tr Tf	50% CTL to 95% Voltage 50% CTL to 5% Voltage 10% - 90% 90% - 10%	μs	_	3.1 0.2 2.6 0.08	_

- 10. The parameters were measured with 500 k Ω R_{BIAS} connecting between pin V_{CC} and pin I_{BIAS}.
- 11. I_{BIAS} is included in the quiescent V_{CC} current due to the bias configuration.
- 12. Switching parameters were measured driving 220 pF capacitors with no current load. Controls C1 and C2 were tied together. It will be faster when C2 is inverted from C1, which is case driving a SPDT switch.

Typ. Ton Driving 220pF Caps vs VDD VCC = 3.3V, IBIAS = 6μA, 25°C



Typ. Ton Driving 220pF Caps vs IBIAS VCC = 3.3V, VDD = 250V, 25°C

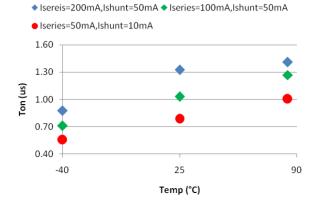




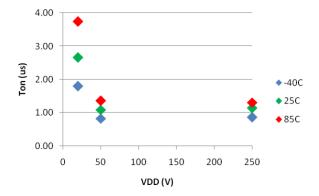
Rev. V4

Performance Driving MACOM MA4P504-1072T PIN Diode SPDT Switch ¹³

Typ. Ton (50% Ctl to 90% RF) VDD=250V, VCC=3.3V, IBIAS=6μA



Typ. Ton (50% Ctl to 90% RF) vs. VDD VCC=3.3V, IBIAS=6μA Iseries=200mA, Ishunt=50mA

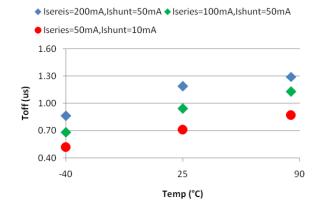


Typ. IDD vs IBIAS at 25°C

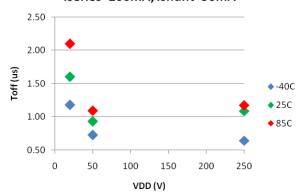
500
400
200
100
0 30 60 90 120 150 180

IBIAS (μΑ)

Typ. Toff (50% Ctl to 10% RF) VDD=250V, VCC=3.3V, IBIAS=6μA



Typ. Toff (50% Ctl to 10% RF) vs. VDD VCC=3.3V, IBIAS=6µA Iseries=200mA, Ishunt=50mA

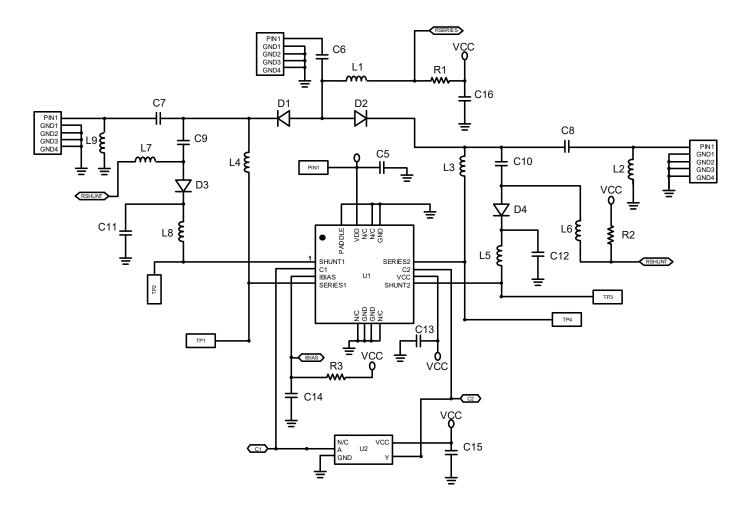


 The switch is a series/shunt, series/shunt SPDT switch using four MACOM MA4P504-1072T PIN diodes. Schematic is on next page. Switching parameters were measured with 500 MHz 20 W CW RF signal.



MADR-010574 Rev. V4

Application Circuit: Driving SPDT Switch with MA4P504-1072T PIN Diodes 14

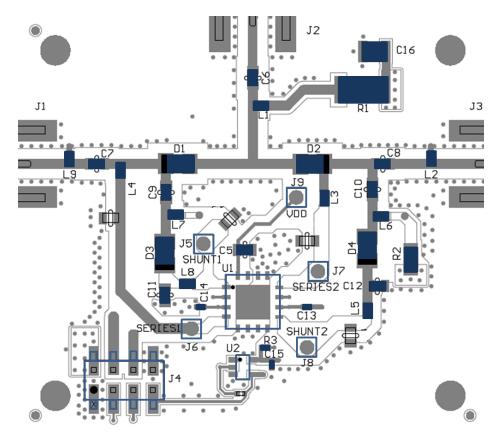


14. This is the schematic of MADR-010547-001SMB. The frequency range for this application circuit is 200 MHz to 500 MHz. The bias current for the series diodes is 200 mA. The bias current for the shunt diodes is 50 mA. The recommended inductors are Coil Craft 0603LS-181XJLB for both current and frequency considerations. For different frequency applications, both capacitors and inductors should be adjusted accordingly.



Rev. V4

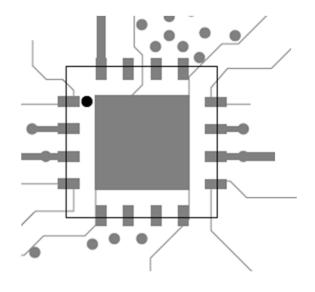
Recommended PCB



Parts List

Part	Value	Size	
C5	0.01 μF, 500 V	0805	
C6 - C12	100 pF, 500 V	0805	
C13 - C15	0.1 μF, 16 V	0402	
L1 - L8	180 nH	0603	
R1	1.5 Ω, 1 W	2512	
R2	15 Ω, 0.5 W	1206	
R3	499 KΩ, 1/16 W	0402	
U2	SN74AHC1GU04DBVR		
D1 - D4	MA4P504-1072		

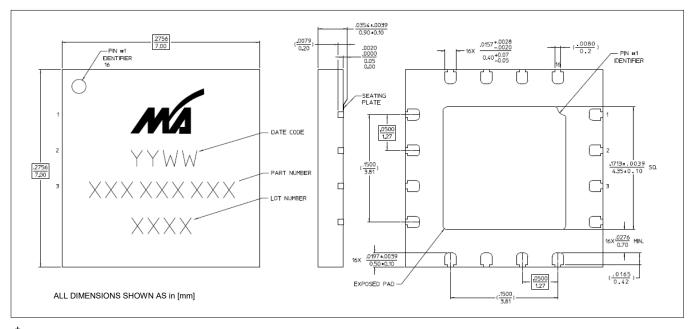
Footprint





Rev. V4

Lead Free 7 mm PQFN-16LD †



[†] This is not a JEDEC standard package. Please refer to Application Note for footprint and lead-free solder reflow recommendations.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

20 V - 250 V Driver for High Power PIN Diode Switches



MADR-010574

Rev. V4

MACOM Technology Solutions Inc. ("MACOM"). All rights reserved.

These materials are provided in connection with MACOM's products as a service to its customers and may be used for informational purposes only. Except as provided in its Terms and Conditions of Sale or any separate agreement, MACOM assumes no liability or responsibility whatsoever, including for (i) errors or omissions in these materials; (ii) failure to update these materials; or (iii) conflicts or incompatibilities arising from future changes to specifications and product descriptions, which MACOM may make at any time, without notice. These materials grant no license, express or implied, to any intellectual property rights.

THESE MATERIALS ARE PROVIDED "AS IS" WITH NO WARRANTY OR LIABILITY, EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, INFRINGEMENT OF INTELLECTUAL PROPERTY RIGHT, ACCURACY OR COMPLETENESS, OR SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES WHICH MAY RESULT FROM USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.